



Development of Nb NanoSQUIDs Based on SNS Junctions for Operation in High Magnetic Fields

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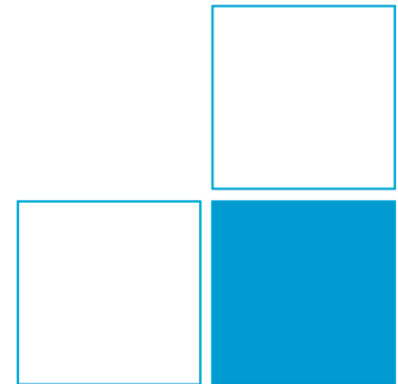
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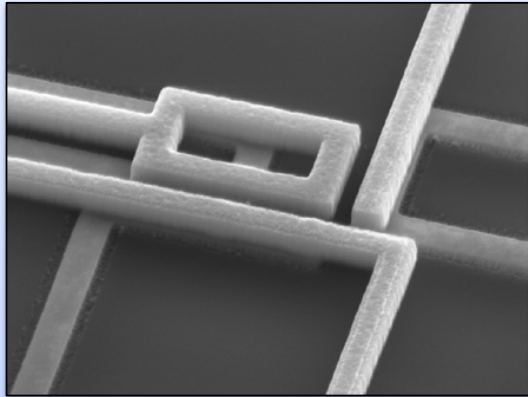




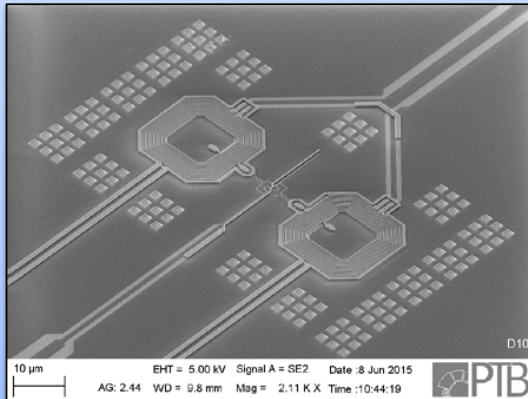
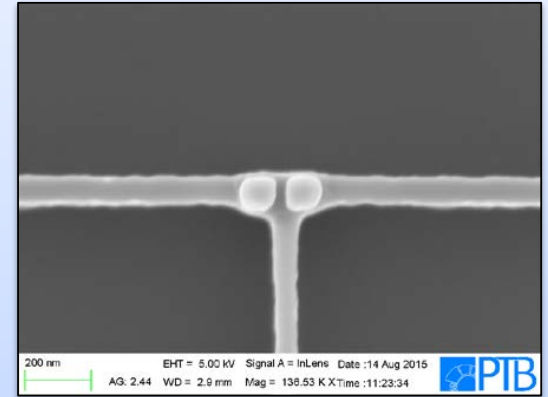




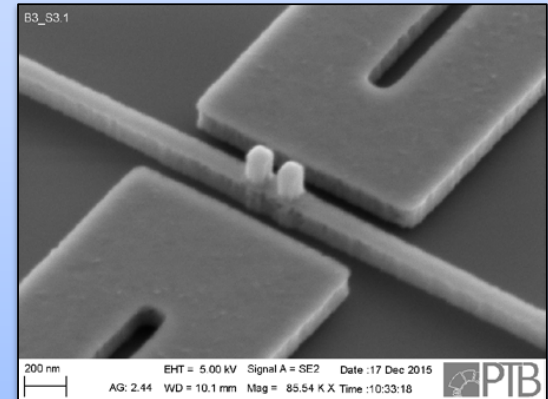
Outline



Motivation
Technology



Results
Outlook





Motivation

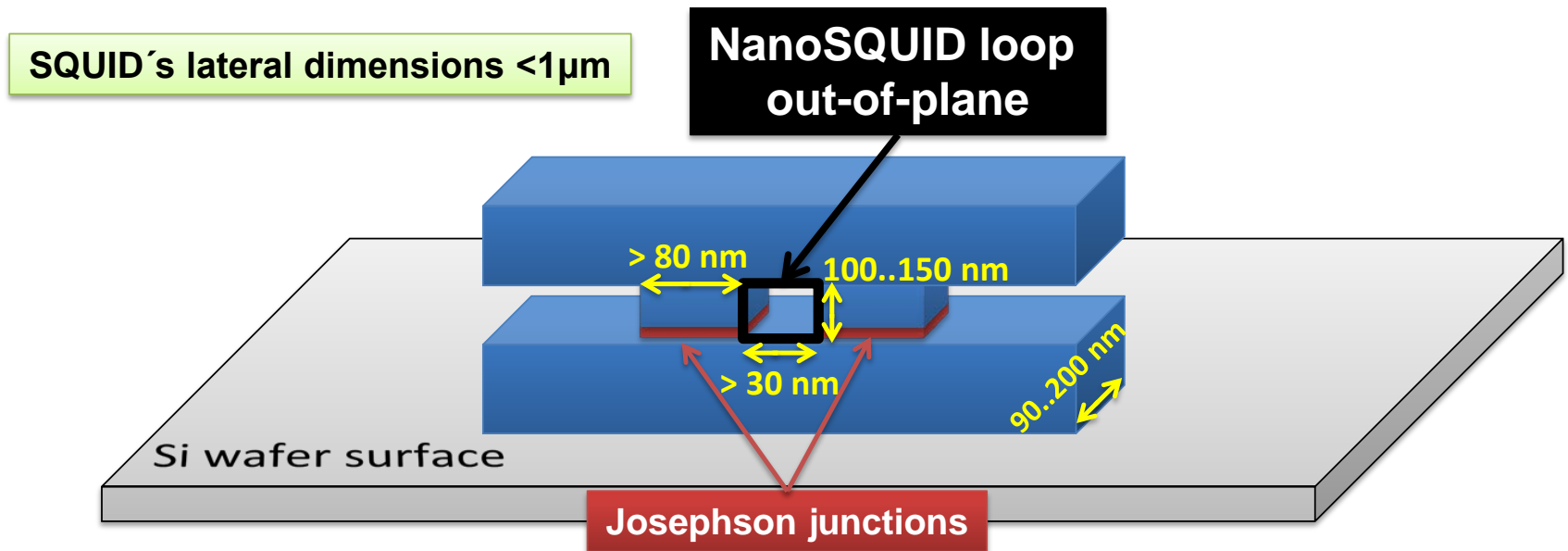
C. Granata and A. Vettoliere, “Nano Superconducting Quantum Interference device: A powerful tool for nanoscale investigations,” *Phys. Rep.*, vol. 614, pp. 1–69, 2016.

Why we use **SNS** instead of **SIS**?

- critical current densities about 1000 times higher (up to about 1 MA/cm²)
- no need for external shunt resistor enables downscaling of the SQUID sensor to sub- μm size
- very small junction capacitance keeps the $\beta_c < 1$ (non-hysteretic IV)



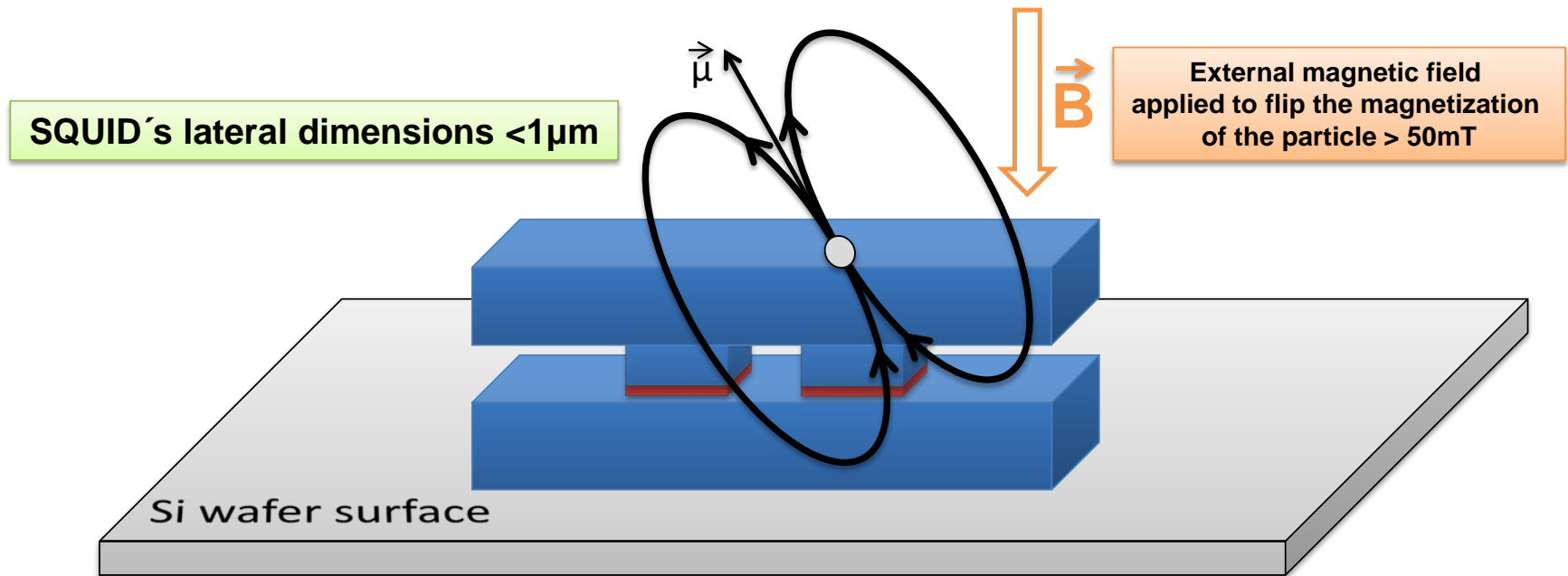
Motivation: Our NanoSQUID



- **High spatial resolution** for localization of MNP
- **High stability** to external magnetic fields
- **Better coupling** to the field of the magnetic particle



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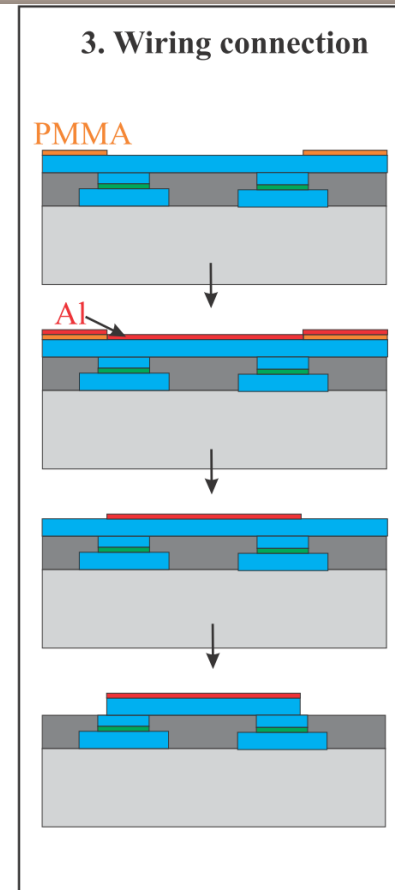
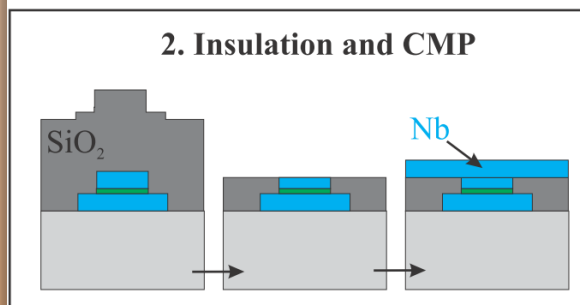
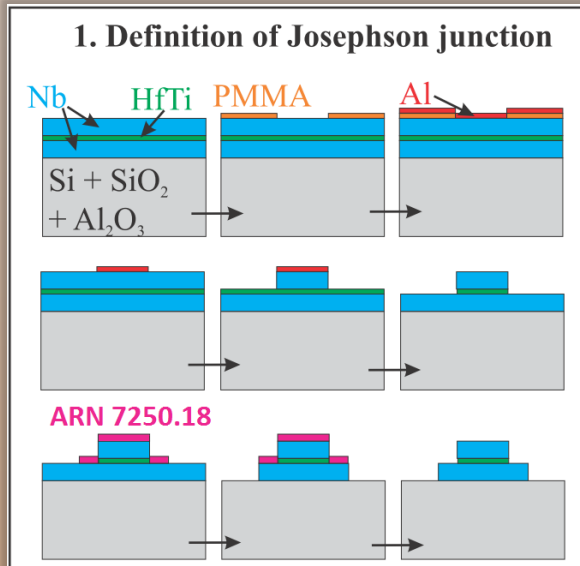
Technology: SNS with HfTi Barrier



electron-beam-lithography
high alignment precision



chem.- mechan. Polishing (CMP)
planar layer interconnection



- designs with high complexity and high yield are feasible
- in-plane and out-of-plane loop orientations in one device



Advanced Technology



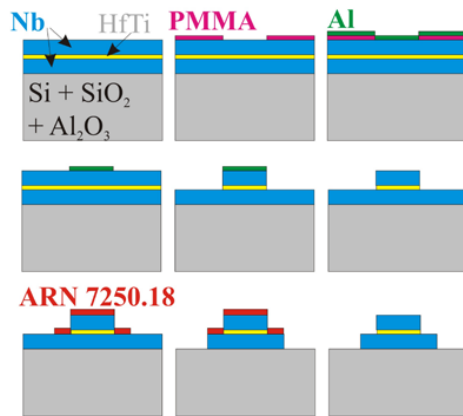
electron-beam-lithography
high alignment precision



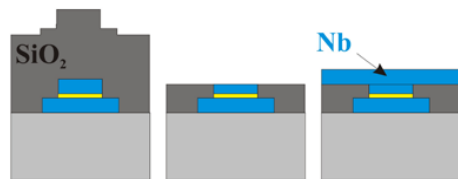
chem.- mechan. Polishing (CMP)
planar layer interconnection

- Layer structure is extended by an additional Nb layer for auxiliary components (coils, transformers)
- It offers more free space and more freedom in designing of superconductive devices

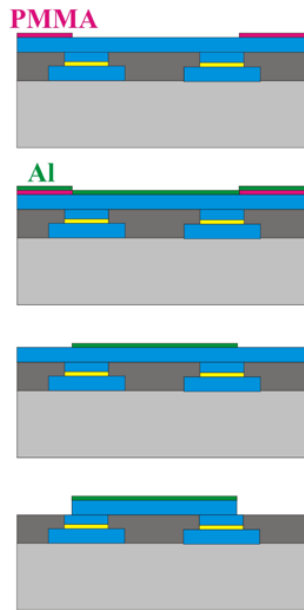
1. Definition of Josephson junction



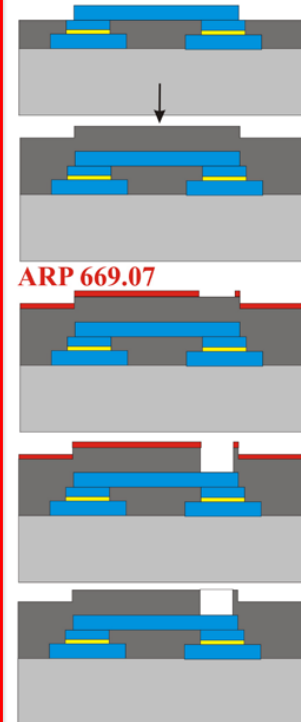
2. Insulation and CMP



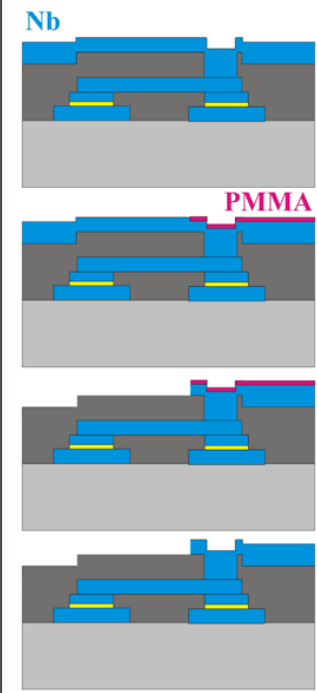
3. Wiring connection



4. Insulation and Via



5. 2nd Wiring connection



Results Related to our Technology

- J. Nagel, O.F. Kieler, T. Weimann, R. Wölbing, J. Kohlmann, A.B. Zorin, R. Kleiner, D. Koelle, and M. Kemmler, “Superconducting quantum interference devices with submicron Nb/HfTi/Nb junctions for investigation of small magnetic particles”, *Appl. Phys. Lett.* **99** (2011) 032506 (3 pp).
- R. Wölbing, J. Nagel, T. Schwarz, O. Kieler, T. Weimann, J. Kohlmann, A. B. Zorin, M. Kemmler, R. Kleiner, and D. Koelle, “Nb nano superconducting quantum interference devices with high spin sensitivity for operation in magnetic fields up to 0.5 T”, *Appl. Phys. Lett.* **102** (2013) 192601 (4 pp).
- A. Buchter, J. Nagel, D. Ruffer, F. Xue, D.P. Weber, O.F. Kieler, T. Weimann, J. Kohlmann, A.B. Zorin, E. Russo-Averchi, R. Huber, P. Berberich, A. Fontcuberta i Morral, M. Kemmler, R. Kleiner, D. Koelle, D. Grundler, and M. Poggio, “Reversal mechanism of an individual Ni nanotube simultaneously studied by torque and SQUID magnetometry”, *Phys. Rev. Lett.* **111** (2013) 067202 (5 pp).
- J. Nagel, A. Buchter, F. Xue, O. F. Kieler, T. Weimann, J. Kohlmann, A. B. Zorin, D. Ruffer, E. Russo-Averchi, R. Huber, P. Berberich, A. Fontcuberta i Morral, D. Grundler, R. Kleiner, D. Koelle, M. Poggio, and M. Kemmler, “Nanoscale multifunctional sensor formed by a Ni nano-tube and a scanning Nb nanoSQUID”, *Phys. Rev. B* **88** (2013) 064425 (7 pp).
- A. Buchter, R. Wölbing, M. Wyss, O. F. Kieler, T. Weimann, J. Kohlmann, A. B. Zorin, D. Ruffer, F. Matteini, G. Tütüncüoglu, F. Heimbach, A. Kleibert, A. Fontcuberta i Morral, D. Grundler, R. Kleiner, D. Koelle, and M. Poggio, „Magnetization reversal of an individual exchange-biased permalloy nanotube”, *Phys. Rev. B* **92** (2015) 214432 (7 pp).
- S. Bechstein, F. Ruede, D. Drung, J.-H. Storm, O. F. Kieler, J. Kohlmann, T. Weimann, and T. Schurig, „HfTi-nanoSQUID gradiometers with high linearity”, *Appl. Phys. Lett.* **106** (2015) 072601 (4 pp)
- J. Beyer, M. Klemm, J. H. Storm, O. Kieler, T. Weimann, V. Morosh, „Noise of dc-SQUIDs with planar sub-micrometer Nb/HfTi/Nb junctions”, *Superc. Sci. Technol.* **28** (2015), 085011.

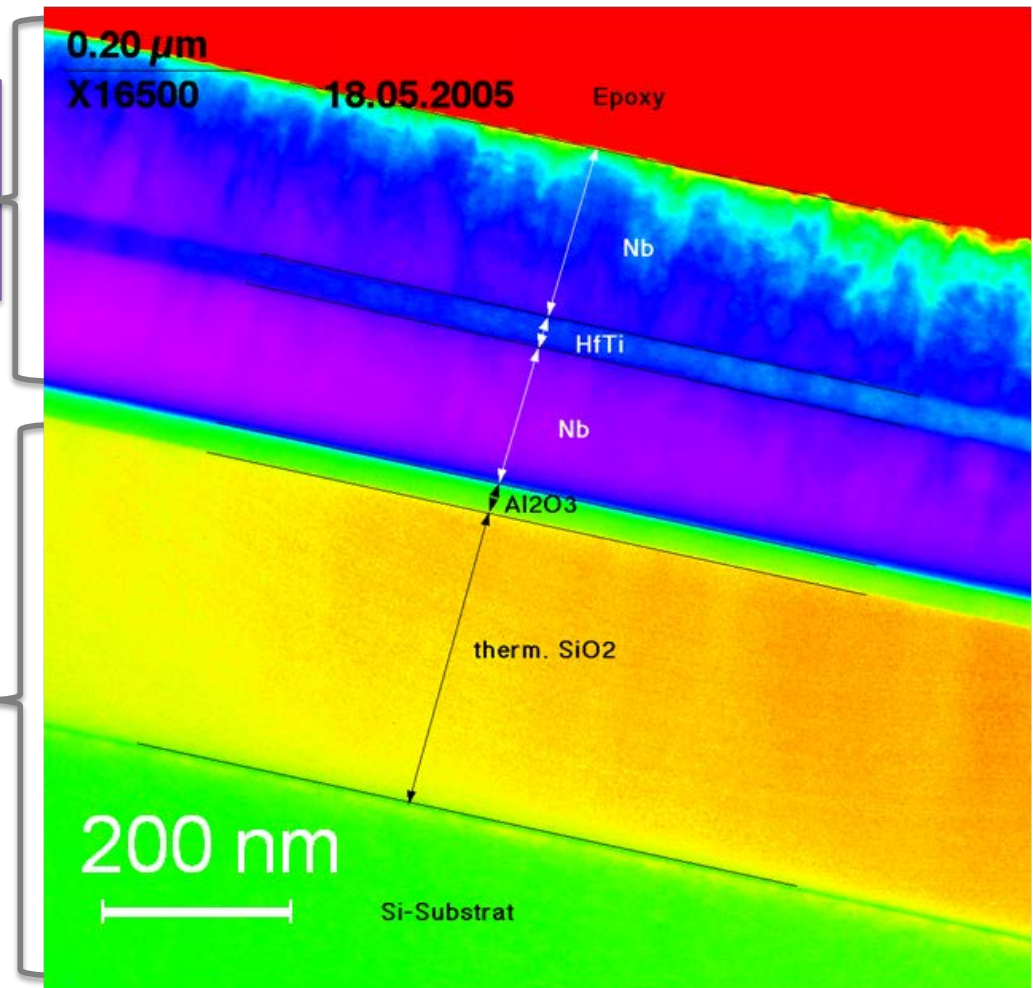
Layer Structure

The Trilayer:

Nb (Top): 200 nm (superconductor)
HfTi: 20...30 nm (normal metal)
Nb (Base): 160 nm (superconductor)

30 nm Al₂O₃ etching stop

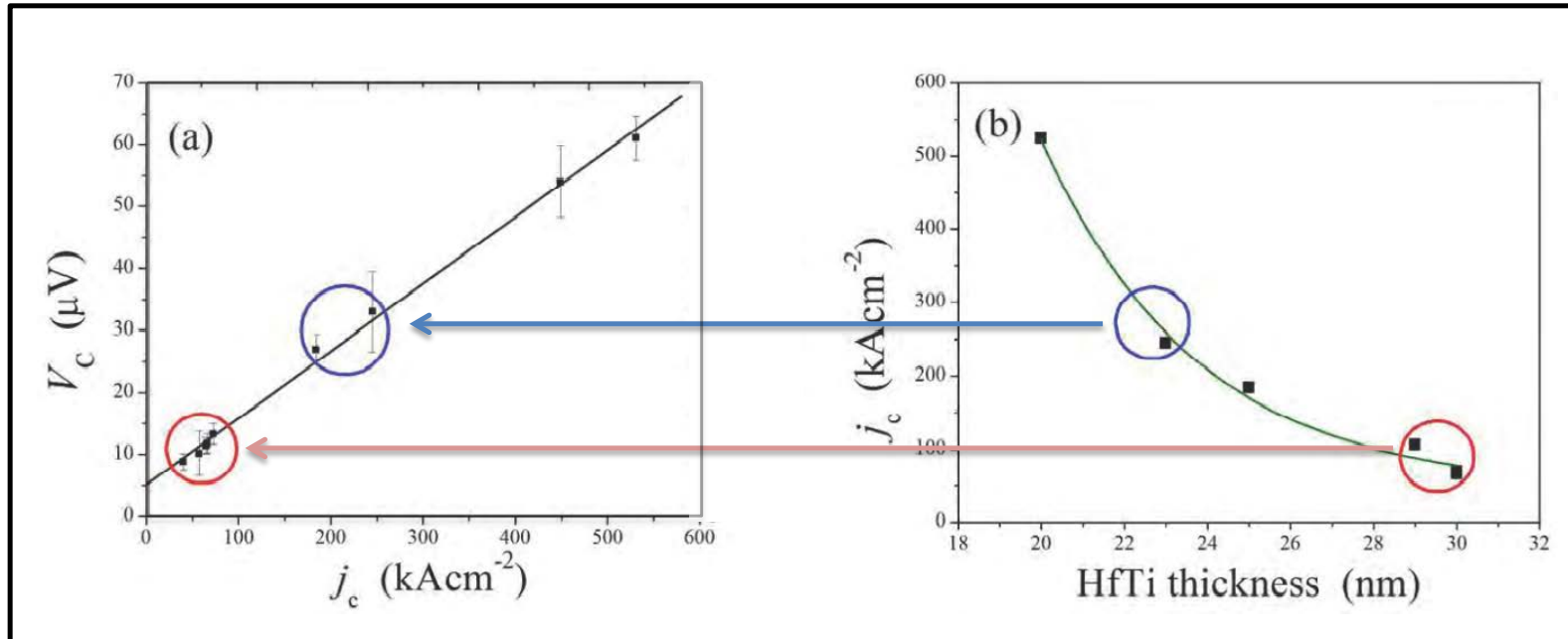
Si substrate with 300 nm thermal oxidized SiO₂



Kieler, O.F.; Iuzzolino, R. & Kohlmann, J. (2009). Sub- μm SNS Josephson junction arrays for the Josephson arbitrary waveform synthesizer, *IEEE Transactions on Applied Superconductivity*, Vol.19, No.3, (June 2009) pp. 230-233.



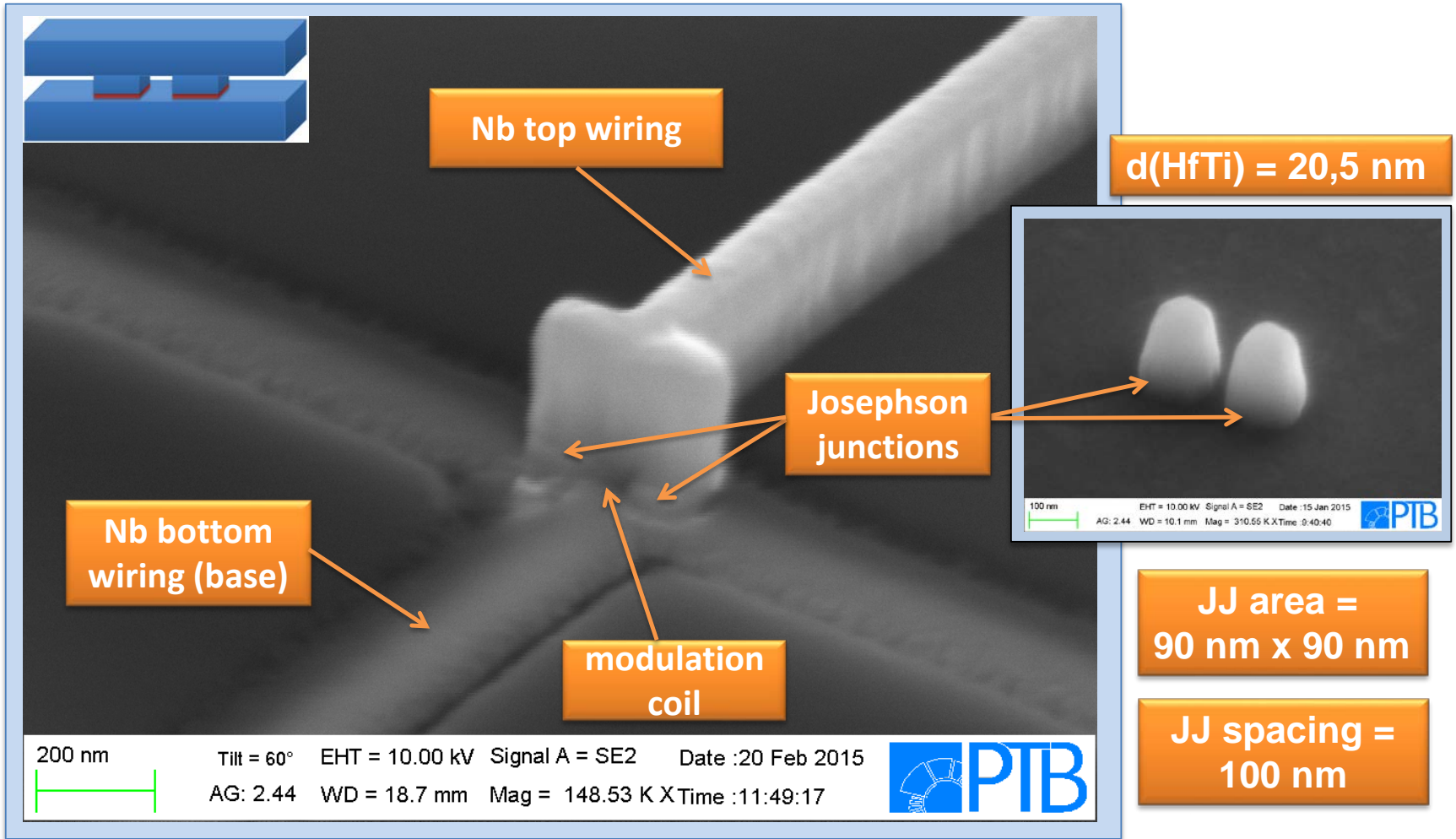
Critical Parameters on Demand



- Parameters of the Josephson junctions can be adjusted
- High reproducibility of the parameters

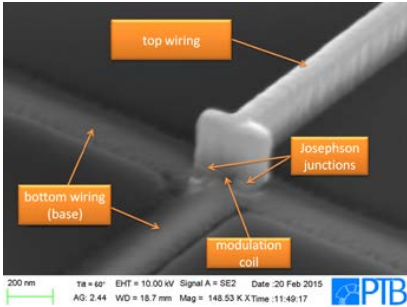


Results: NanoSQUID Type A



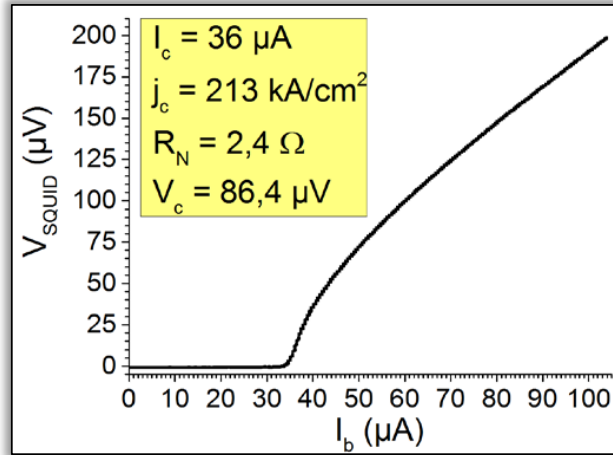


Results: NanoSQUID Type A

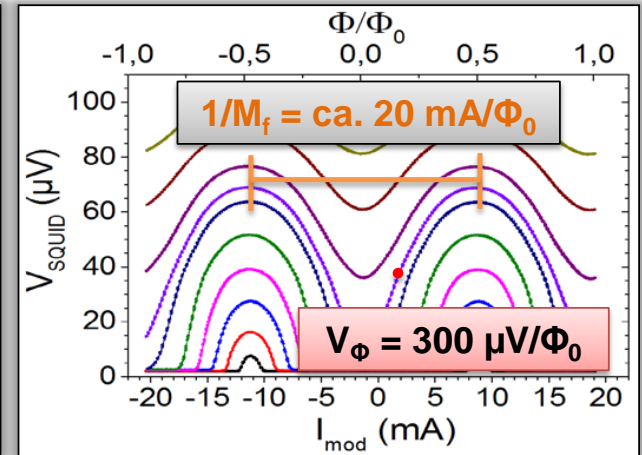


All measurements were made at 4.2 K

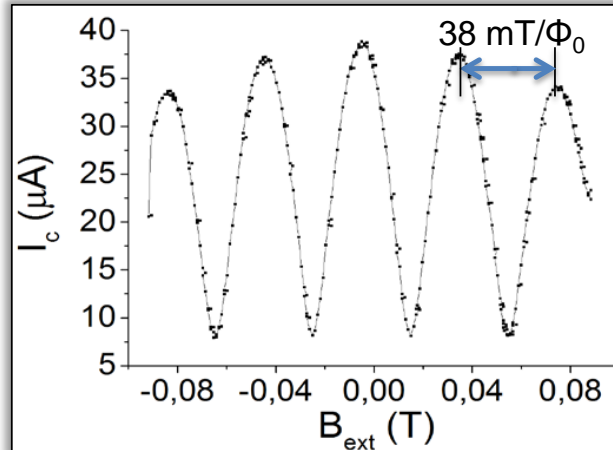
Current-Voltage Characteristics



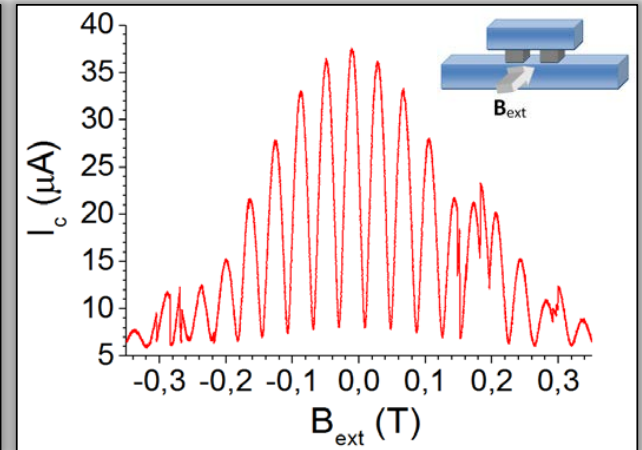
V-Φ- Characteristics



I_c Modulations



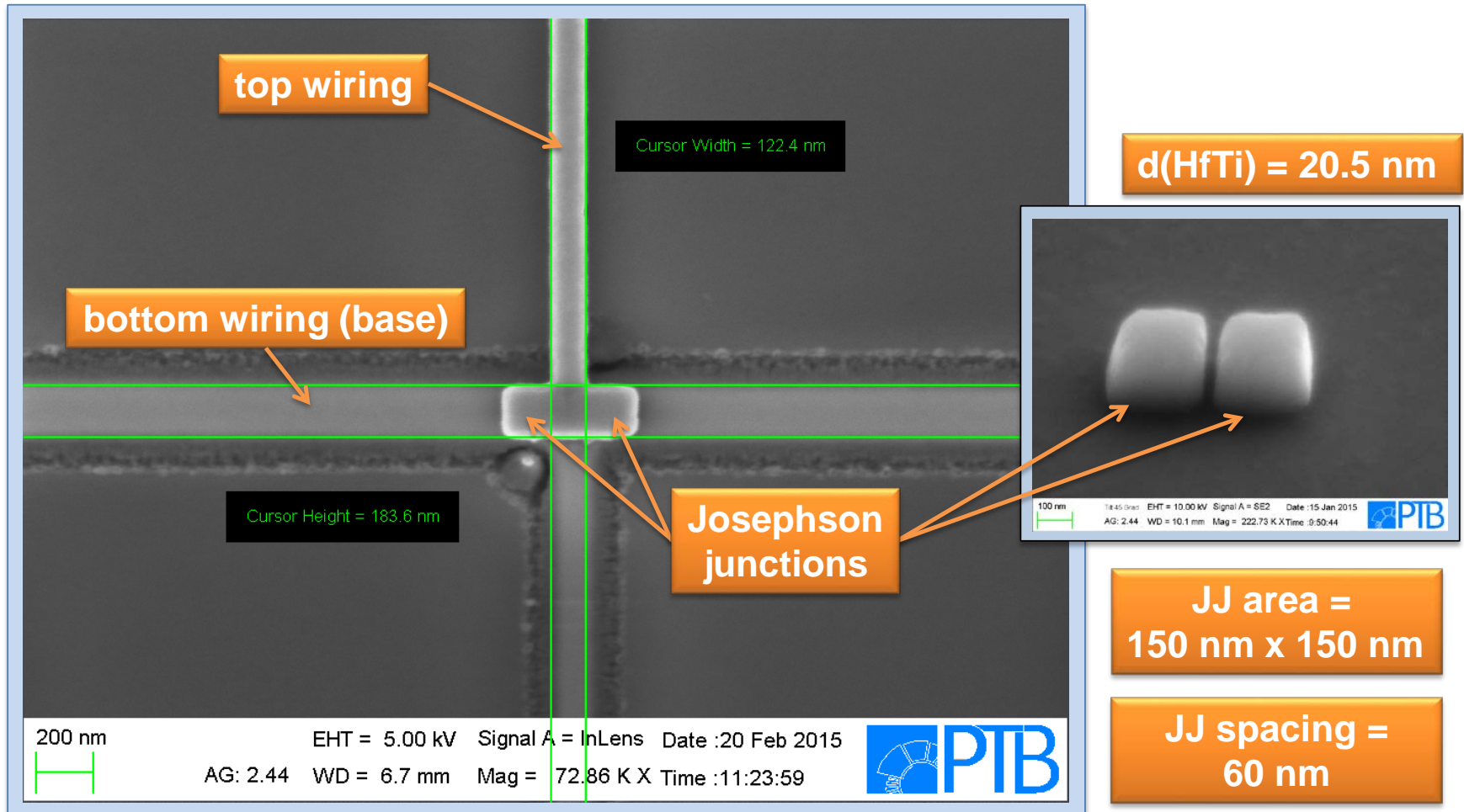
Fraunhofer-Like Pattern



$\beta_L = I_c L / \Phi_0 = 0.2$
 $L = 11 \text{ pH}$
 $\Gamma = 2\pi k_B T / I_0 \Phi_0 = 10 \times 10^{-3}$
 $A_{\text{SQUID,eff}} = 0.05 \text{ } \mu\text{m}^2$
 j_c homogeneous

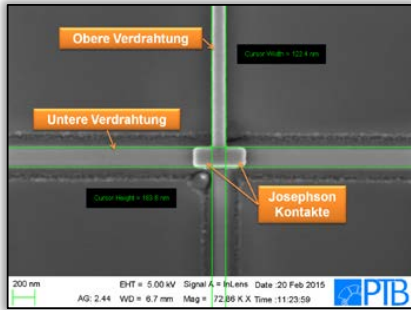


Results: NanoSQUID Type B



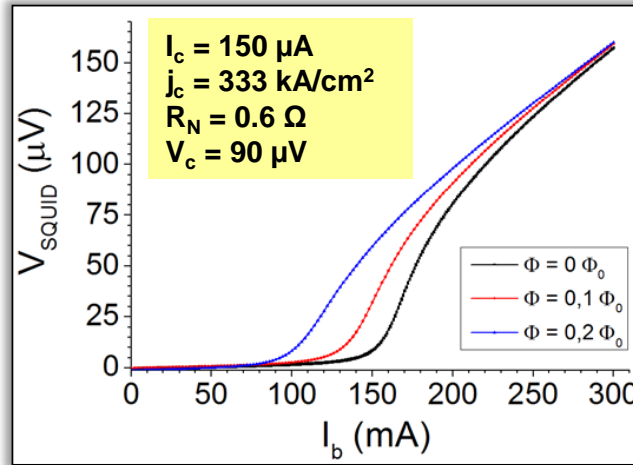


Results: NanoSQUID Type B

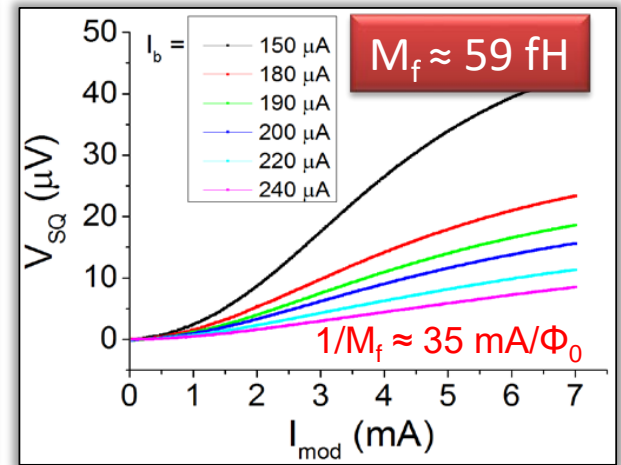


All measurements were made at 4.2 K

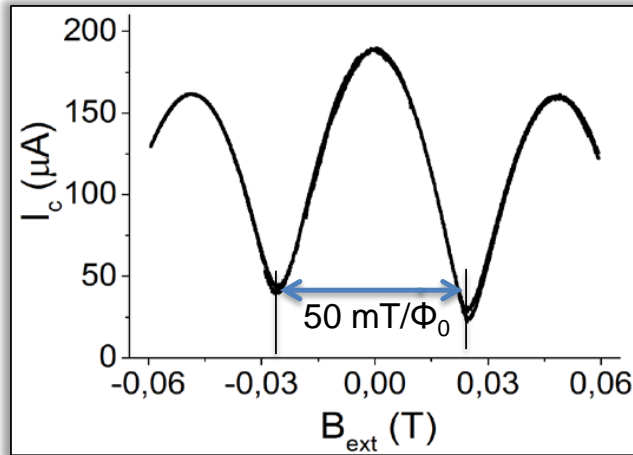
Current-Voltage Characteristics



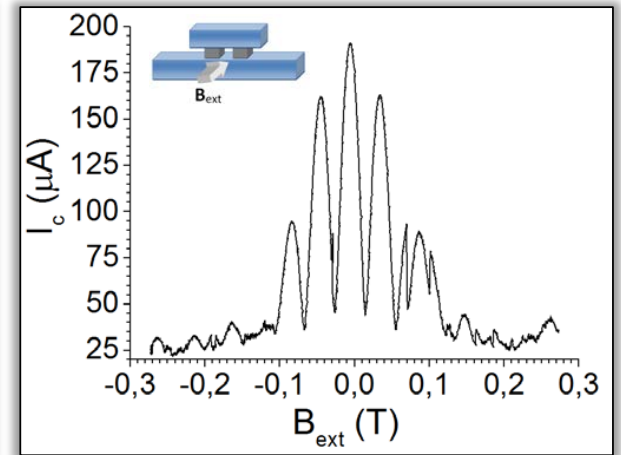
V-I_{mod}- Curve



I_c Modulations



Fraunhofer-Like Pattern

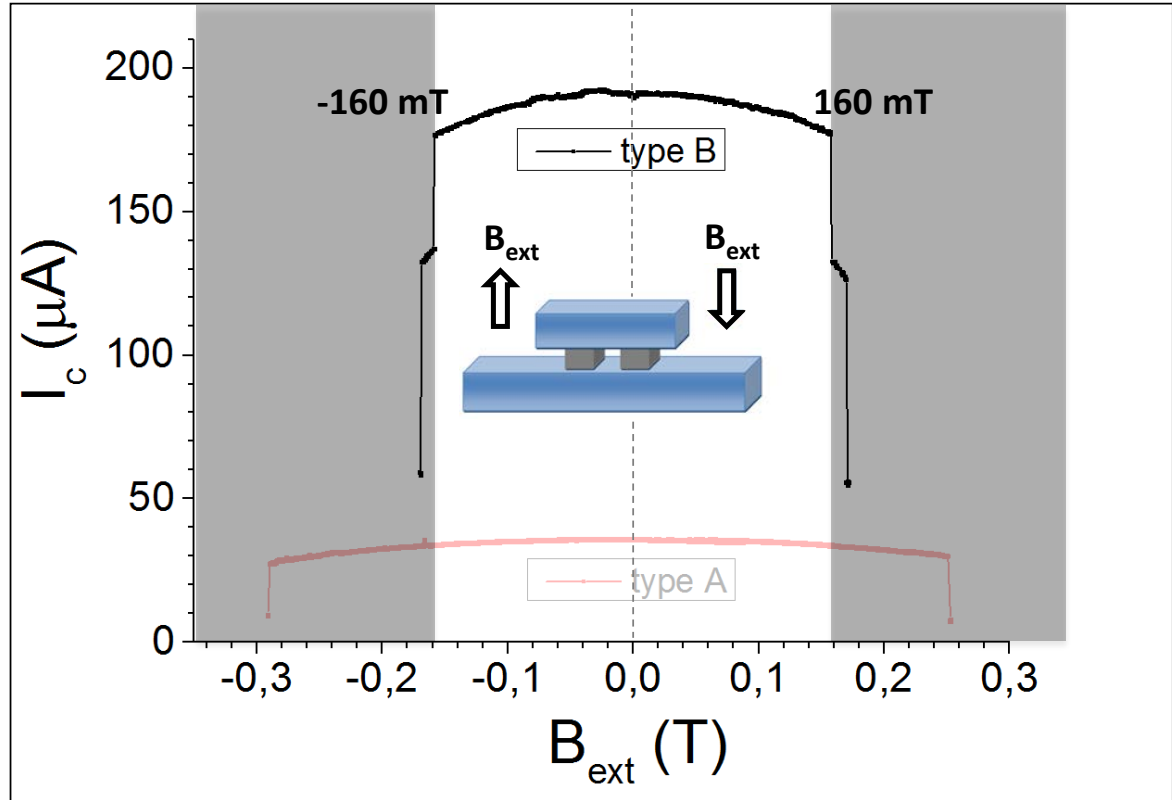
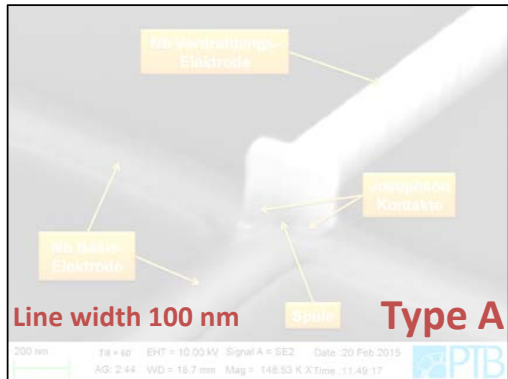
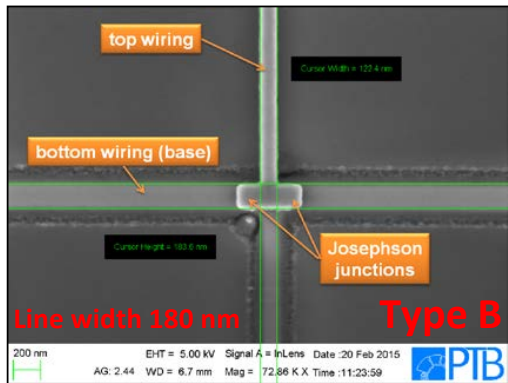


$\beta_L = I_c L / \Phi_0 = 0.25$
 $L = 2.7 \text{ pH}$
 $\Gamma = 2\pi k_B T / I_0 \Phi_0 = 2.3 \times 10^{-3}$
 $A_{\text{SQUID,eff}} = 0.04 \text{ } \mu\text{m}^2$
 j_c homogeneous



Results: NanoSQUID Type A, Type B

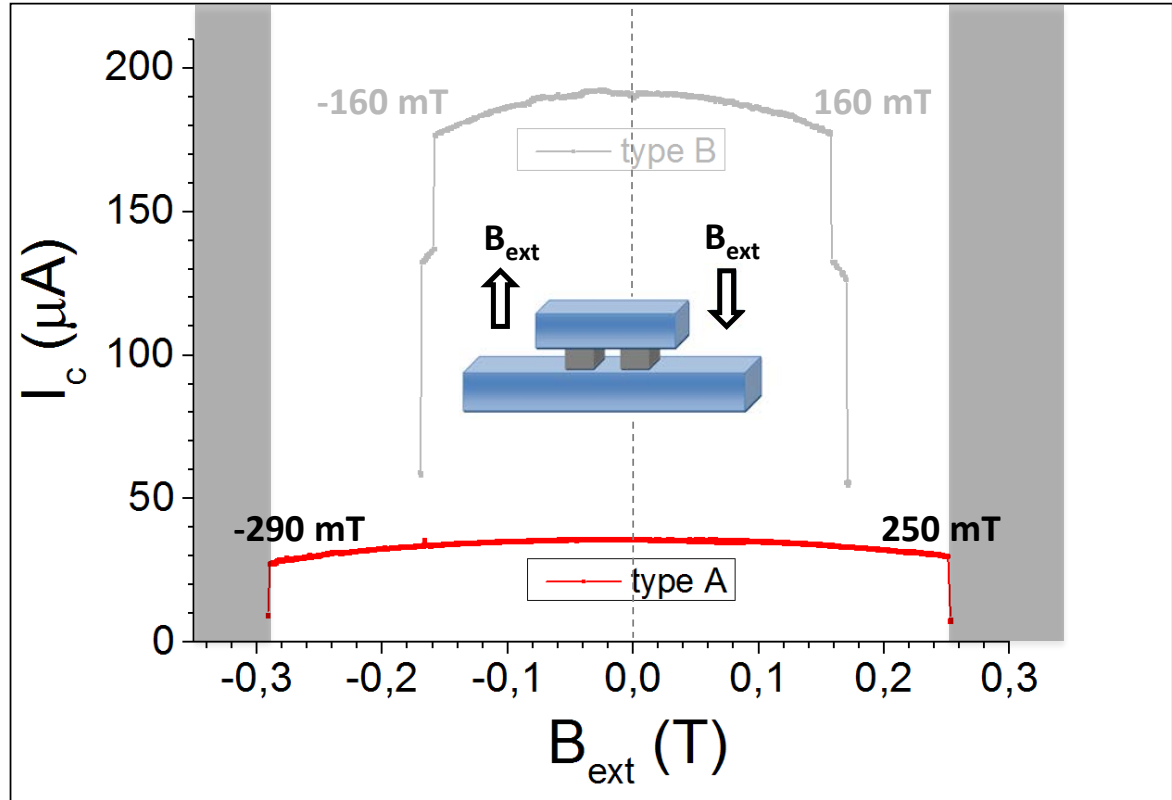
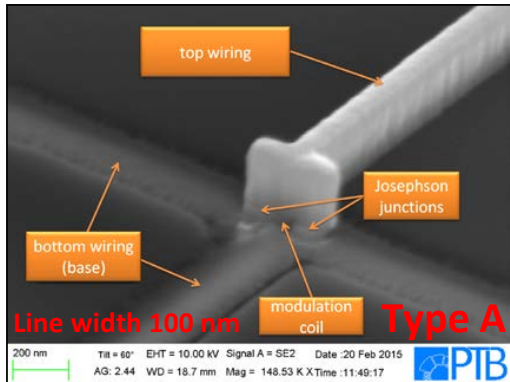
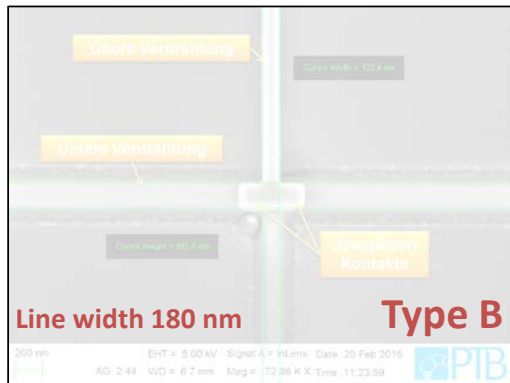
Stability in External Magnetic Field





Results: NanoSQUID Type A, Type B

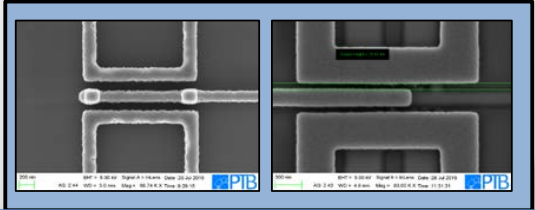
Stability in External Magnetic Field





Results: Type C

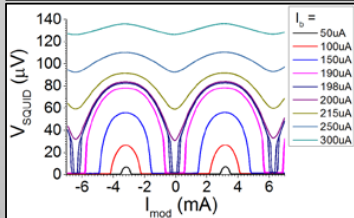
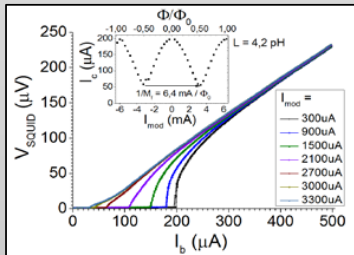
NanoSQUID Sensor Data



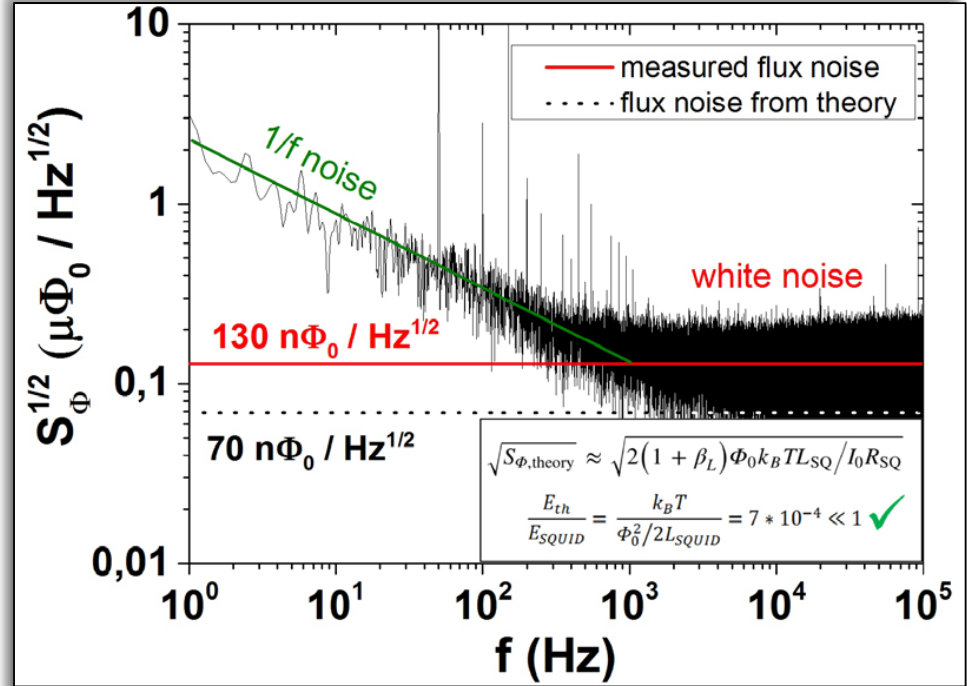
JJ area: 150 nm x 150 nm
 SQUID loop: 1 μm x 100 nm
 Gap (input coil-SQUID): 100 nm

$I_c = 200 \mu\text{A}$
 $R_N = 0.5 \Omega$
 $V_c = 100 \mu\text{V}$
 $i_c = 444 \text{ kA/cm}^2$
 $1/M_f = 6.4 \text{ mA}/\Phi_0$
 $\beta_L = I_c L / \Phi_0 = 0.4$
 $L = 4.2 \text{ pH}$
 $A_{\text{SQUID}} = 0.1 \mu\text{m}^2$

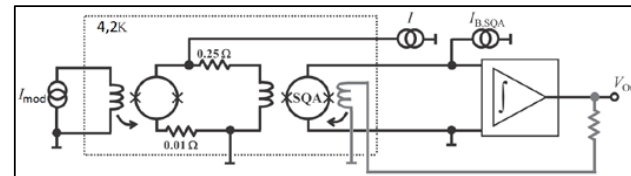
Very high critical current densities!



Flux Noise



2-stage measurement configuration



$$S_{\mu}^{1/2} = S_{\Phi}^{1/2} / \phi_{\mu}$$

10 μ_B / Hz^{1/2}



Voltage Noise of Single JJs

Johnson-Nyquist Noise:

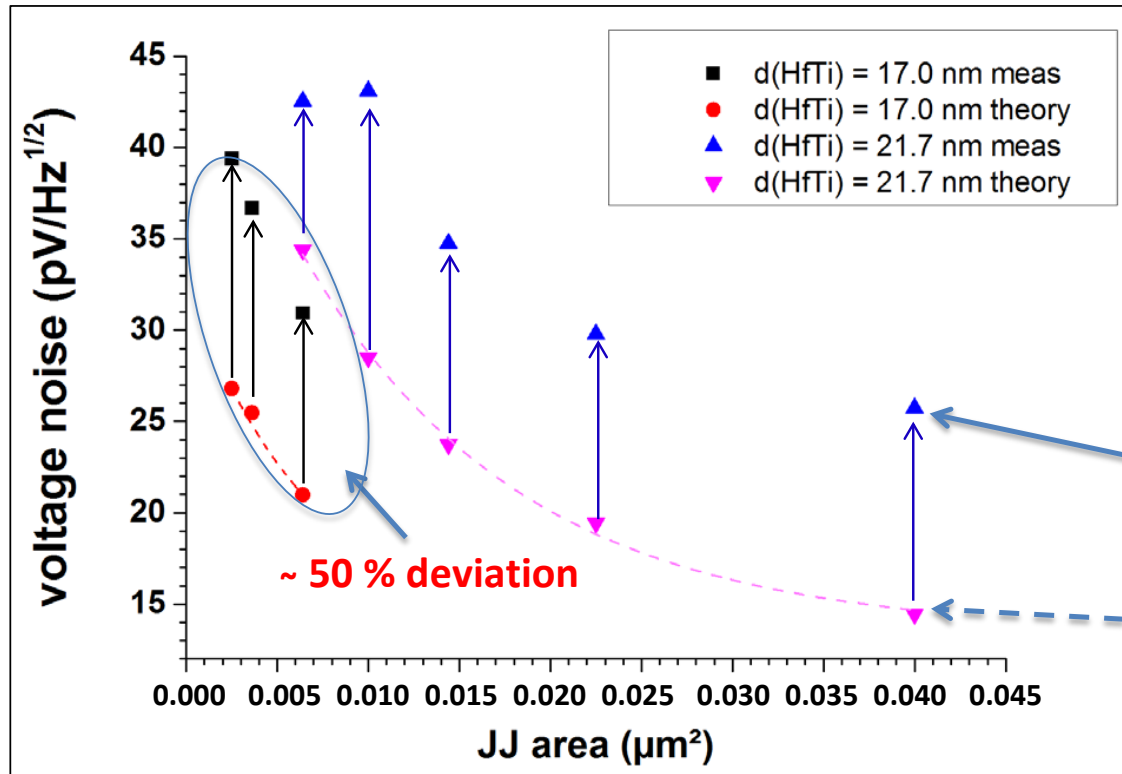
$$S_V^{1/2} = (4k_B T R_N)^{1/2}$$

Bath temperature:

$$T = 4.2 \text{ K}$$

Effective JJ Temperature:

$$T_{JJ \text{ eff.}} \approx 9 \text{ K}$$



measurement

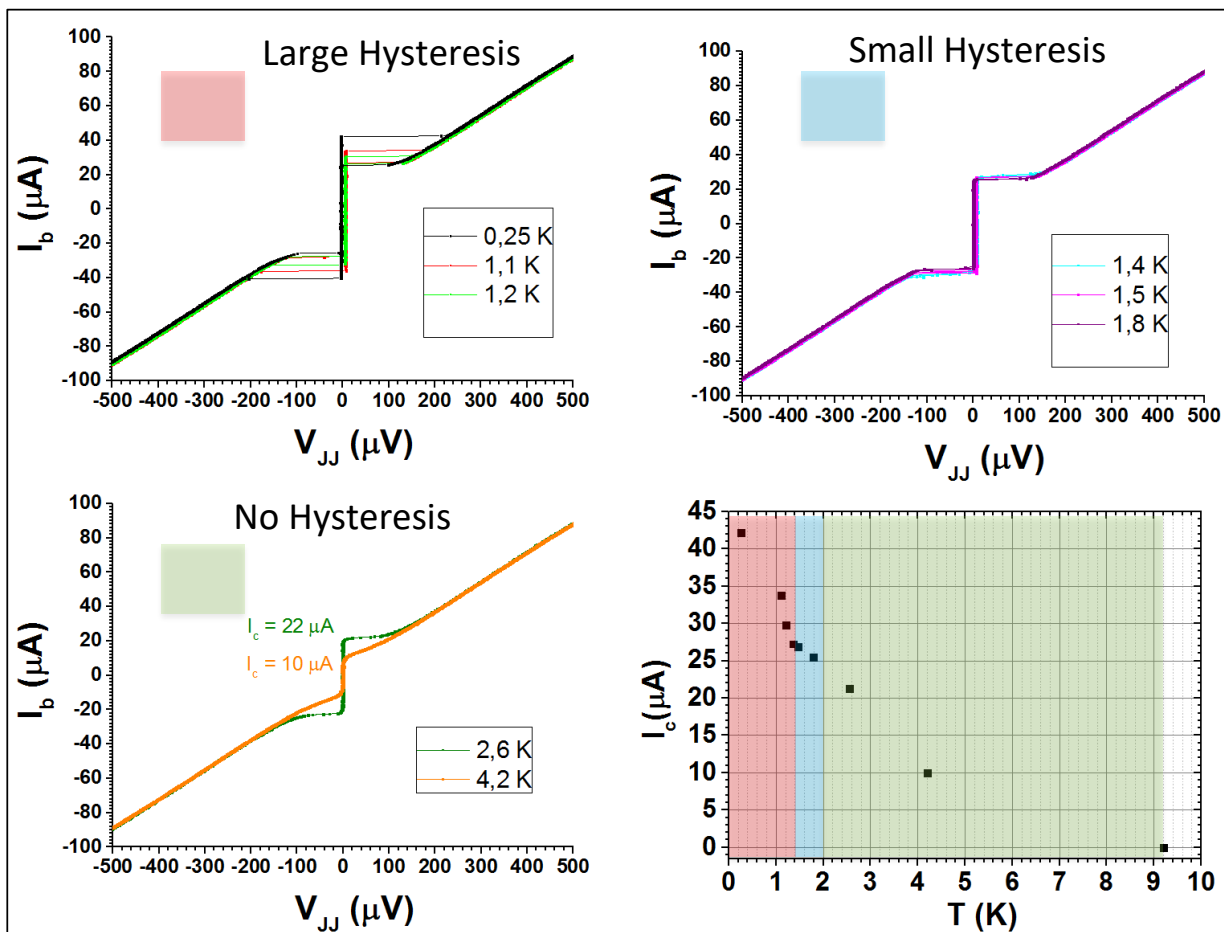
~ 60 % deviation

theory

Similar self-heating effect in Nb/HfTi/Nb SQUID devices was reported in:

- ❖ J. Beyer, M. Klemm, J. H. Storm, O. Kieler, T. Weimann, V. Morosh, „Noise of dc-SQUIDs with planar sub-micrometer Nb/HfTi/Nb junctions”, Superc. Sci. Technol. 28 (2015), 085011.

Temperature Behavior of a Single JJ



JJ: 80 nm x 80 nm

$d(\text{HfTi}) = 20.5 \text{ nm}$

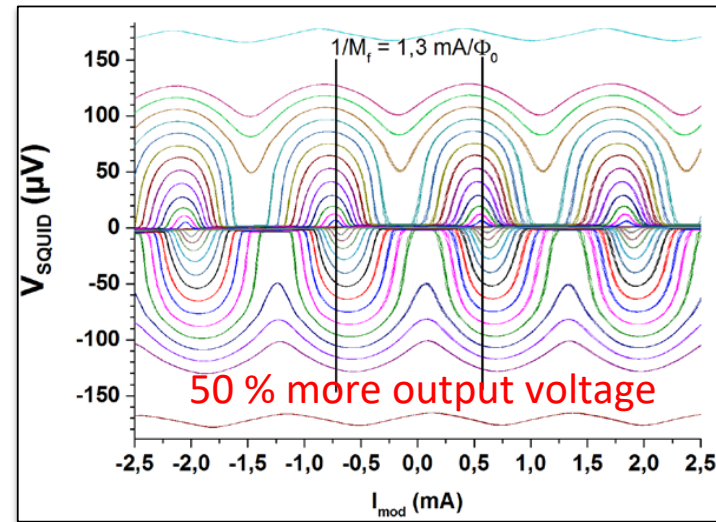
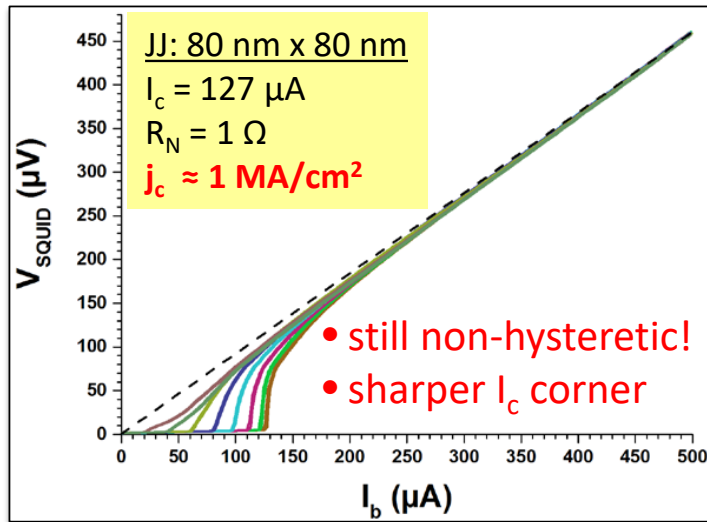
$R_N = 6.2 \Omega = \text{const}$

SQUIDs nonhysteretic:
1.4 K....4.2 K !



High Critical Current Density j_c

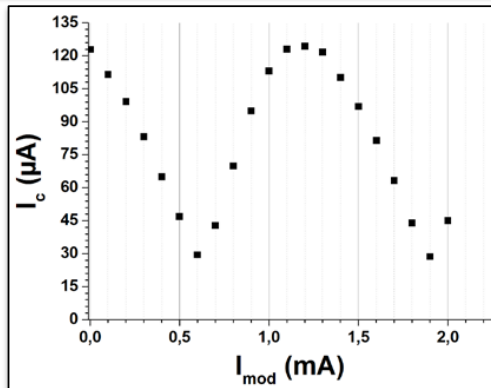
All measurements are made at $T = 4.2$ K



$$\beta_L = I_c L / \Phi_0 \approx 0.3$$

↓

$$L \approx 5 \text{ pH}$$

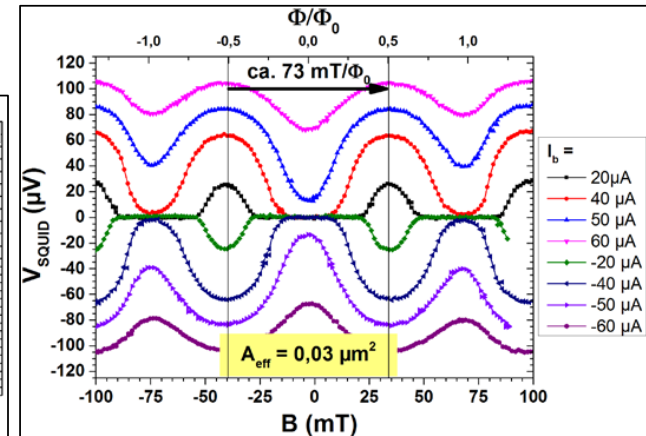
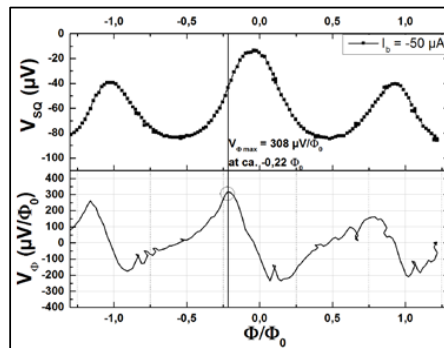
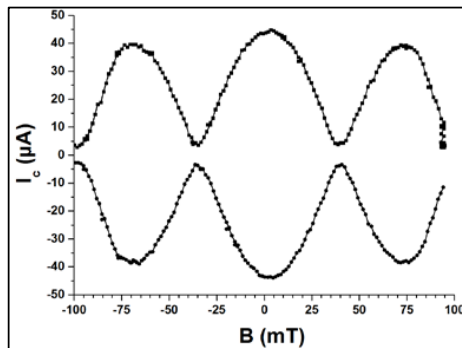
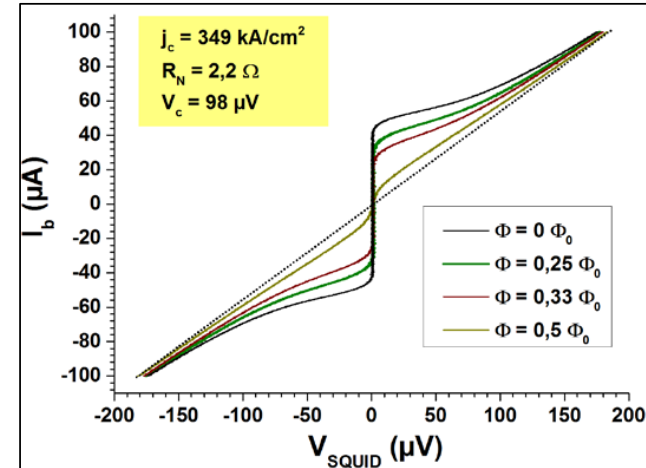
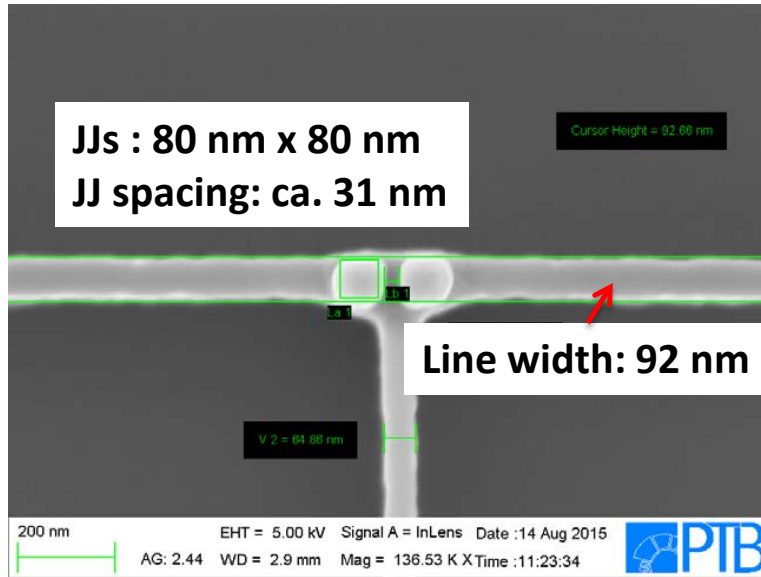


Comparison of the Gamma parameter

$$\Gamma = 2\pi k_B T / I_0 \Phi_0$$

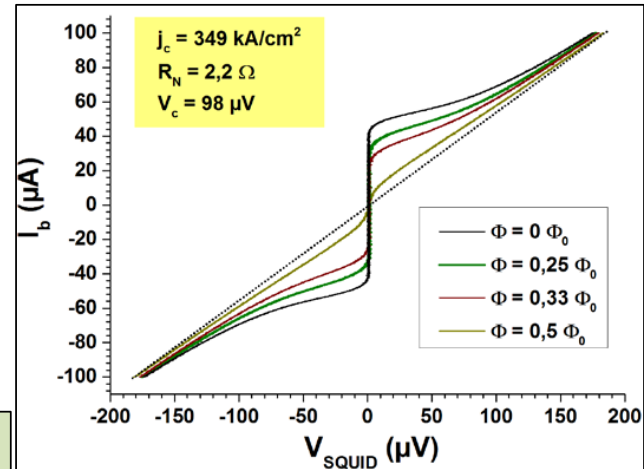
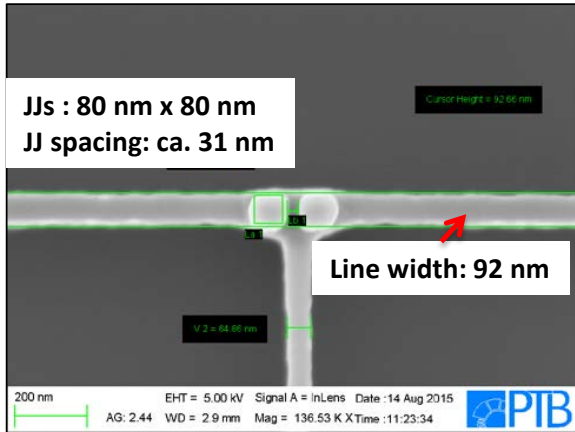
Type A ($j_c = 213 \text{ kA/cm}^2$)	This nanoSQUID ($j_c = 1 \text{ MA/cm}^2$)
10×10^{-3}	$2,7 \times 10^{-3}$

Our Smallest NanoSQUID



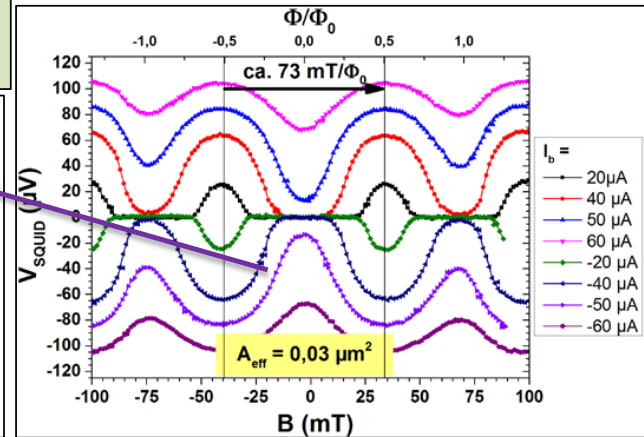
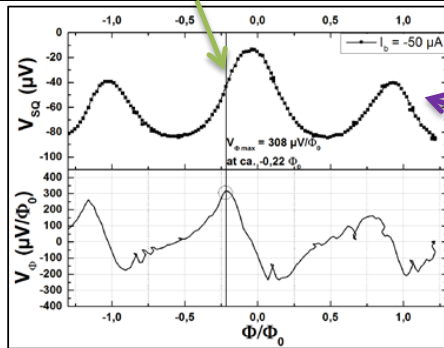
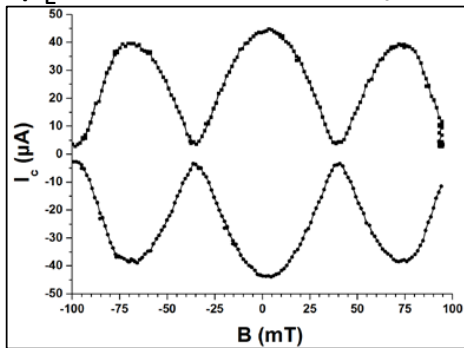
All measurements are made at $T = 4.2 \text{ K}$

Our Smallest NanoSQUID



Optimal working point:
 $V_\Phi = 308 \mu\text{V}/\Phi_0$ at
 $\Phi = -0,22 \Phi_0, I_b = -50 \mu\text{A}$

$\beta_L \approx 0,1 \rightarrow L \approx 5,1 \text{ pH}$



All measurements are made at $T = 4.2 \text{ K}$

Summary and Outlook

- effective area down to $0,03 \mu\text{m}^2$, JJ spacing down to 31 nm
- Josephson junctions down to $80 \times 80 \text{ nm}^2$
- narrow line width 92 nm
- stability in high magnetic fields up to 290 mT
- low level of white noise $130 \text{ n}\Phi_0 / \text{Hz}^{1/2}$
- spin sensitivity: $10 \mu_B / \text{Hz}^{1/2}$ → towards single spin sensitivity
- noise properties in applied magnetic fields and at different temperatures
- simulation of the optimum parameters using experimental data

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B. Egeling**

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Thank you



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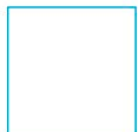


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Stand: 10/16